

Innovative High Power Solutions



High Power (HP) DC-DC Product Selection Guide

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Applications • Car Chargers for Smart Phones, iPad / iPhone / iPod, PND , and tablet PCs • LCD-TV, Set-Top Box, ADSL, Monitor • Data Storage • Digital Video Recorder and Security Camera • LED Lighting • DC-DC PRODUCT SELECTION CLUDE								
Part	Tomology	Input Voltage	Output Current	Feedback	Switching	Berlen	Amplications	
Number	Topology	· (V)	(A)	Voltage (V)	Frequency	Раскаде	Applications	
ACT4501	Async Buck	10 to 30 (40V surge)	1.25	0.808	125KHz	SOP-8	5V/1.0A Car Charger	
ACT4515	Async Buck	10 to 40	1.5	0.808	210kHz	SOP-8	5V/1-1.4A Car Charger	
ACT4513	Async Buck	10 to 40	2.0	0.808	210kHz	SOP8-EP	5V/1.2-1.8A Car Charger	
ACT4523	Async Buck	10 to 40	3.0	0.808	225kHz	SOP8-EP	5V/1.5-2.1A Car Charger	
ACT4303	Async Buck	10 to 30	3.0	0.808	225kHz	SOP8-EP	USB Charger with AC adap- tors, LCD-TV	
ACT4455	Async Buck	7.5 to 36 (40V surge)	5.0	0.800	200kHz	SOP8-EP	5V/2.1A+2.1A and 5V/2.1A+1.0A Dual-Output Car Chargers, LCD-TV, Automotive	
ACT2102	Sync Buck	4.5 to 18	2.0	0.923	310kHZ	SOP-8	LCD-TV, ADSL, Set-Top Box, Monitor	
ACT2103	Sync Buck	4.5 to 18	3.0	0.923	310kHZ	SOP-8EP	LCD-TV, ADSL, Set-Top Box, Monitor	
ACT2113	Sync Buck	4.5 to 18	3.0	0.923	510kHZ	SOP-8EP	LCD-TV, ADSL, Set-Top Box, Monitor	
ACT4060B	Sync Buck	4.5 to 18	2.0	0.923	350kHz	SOP8-EP	LCD-TV, ADSL, Set-Top Box, Monitor	
ACT4065A	Async Buck	6.0 to 30	2.0	0.808	210kHz	SOP-8	Car Charger, Networking, Set- Top Box, Black box	
ACT4070B	Async Buck	6.5 to 30	3.0	0.808	300kHz	SOP-8EP	Car Charger, Networking, Set- Top Box, Black box	
ACT4088	Async Buck	4.5 to 28	1.5	0.810	1.4MHz	SOT23-6	ADSL, Set-Top Box	
ACT111A	Async Buck	4.5 to 30	1.5	0.100	1.4MHZ	SOT23-6	LED Lighting, LED Display	

Demo Board Introduction

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5. ACT4455 5V/3.1A Dual-Output Car Charger	.11
6. ACT4455 5V/4.2A Dual-Output Car Charger	.13
7. ACT111A VIN=12VDC or AC, 3x350mA LEDs	.15

For information regarding Active-Semi products, sales and authorized distributors, please contact: sales@active-semi.com.



ACT4501 5V/1.0A Smart Phone Car Charger

Input Voltage	Device	Standby Power	Output	Efficiency	Topology
10-28V	ACT4501	60mW@12Vin	5V@1.0A	88%@1A , Vin=12V	Buck



L=30.5mm W=14.5mm H=12.8mm

Design Features

- Wide input voltage range from 10V to 28V ٠
- Transparent input voltage surge 12V-40V-12V
- 1A-1.5A output current limit
- 4.75V-5.25V during input and load transients ٠
- 5% output voltage accuracy ٠
- 125kHz switching frequency .
- 88% efficiency at 12V input
- Least external components
- Low-cost single layer PCB with very good EMC performance

Operation and Application

ACT4501 is a step-down DC-DC converter with wide input voltage range and high efficiency dedicated to 5V/1A smart phone micro car chargers. The ACT4501 is internally optimized for good EMC performance and it passed radiated EMI test even on low-cost single layer PCBs without adding any EMC components.

Figure 1:



Schematic of Charger

ACT4501 provides constant current (CC) output with patented Active-CC control technology that eliminate external sense resistors and the related efficiency loss.

The ACT4501 operates at constant output voltage mode until it reaches the CC limit set by the ISET resistor. The devices are available in a SOP-8 package.

Key Component Selection

Higher output inductance reduces the inductor peak -to-peak current at the expense of higher larger core size and inductance DCR value. Usually, an optimum inductance value is selected to make its peak-to-peak current 20%-40% of the maximum load current. The Schottky diode must have current rating higher than the maximum output current and the reverse voltage rating higher than the maximum input voltage. Output capacitor is selected to keep the peak-to-peak voltage ripple under required value and also meet the load transient requirements. Usually, the combination of low ESR capacitors and tantalum or electrolytic types are used. In this application, 220uF electrolytic capacitor is connected in parallel with a small 2.2µF ceramic capacitor to achieve small output voltage ripple and meet the requirements of input and load dynamic response.



ACT4501 5V/1.0A Smart Phone Car Charger

Bill of Materials

REF	DESCRIPTION	MFTR
L1	Choke Coil, ring core:8*4*5mm,Pi=0.35mm,L=82uH, dip	Haining Electronic- Magnetics
D1	Schottky Diode, B240A,2A/40V, SMA	Diodes
C1	Capacitor,Electrolytic,100uF/35V,Ф7x8mm,Dip	KSC
C2	Ceramic capacitor, 10uF/16V, X7R, 0805	Murata/TDK
C4	Ceramic capacitor, 10nF/25V, X7R, 0603	Murata/TDK
C5	Ceramic capacitor, 2.2nF/25V, X7R, 0603	Murata/TDK
C6	Ceramic capacitor, 100pF/16V, X7R, 0603	Murata/TDK
C7	Ceramic capacitor, 10uF/35V, X7R, 0805	Murata/TDK
C8	Ceramic Electrolytic, 220uF/10V, Ф6.3x7mm, Dip	Murata/TDK
R1	Chip Resistor, 1KΩ, 1/16W, 5%, 0603	Murata/TDK
R2	Chip Resistor, 19.6KΩ, 1/16W, 1%, 0603	Murata/TDK
R3	Chip Resistor, 25KΩ, 1/16W, 1%, 0603	Murata/TDK
R5	Chip Resistor, 51.1KΩ, 1/16W, 1%, 0603	Murata/TDK
R6	Chip Resistor, 9.76KΩ, 1/16W ,5%, 0603	Murata/TDK
RA/RB	Chip Resistor, 49.9KΩ, 1/16W, 1%,0603	Murata/TDK
RC	Chip Resistor, 43.2KΩ, 1/16W, 1%,0603	Murata/TDK
RD	Chip Resistor, 75KΩ, 1/16W, 1%,0603	Murata/TDK
U1	IC, ACT4501 SOP-8	Active semi
USB	15mm*10mm*8mm	USB Manu

PCB Top Layer



PCB Bottom Layer



PC Board Layout Guidance

1) Arrange the power components to reduce the AC loop size that consists of CIN, IN pin, SW pin the Schottky diode.

2) Place input decoupling ceramic capacitor CIN as close to IN pin as possible. CIN is connected power GND with vias or short and wide path.

- 3) Place feedback resistor close to FB pin.
- 4) Use short trace connecting HSB-C4-SW loop.
- 5) SW pad is a noisy node switching from Vin to GND. It

Typical performance characteristics









ACT4515 5V/1.2A Smart Phone Car Charger

Input Voltage	Device	Standby Power	Output	Efficiency	Topology
10-32V	ACT4515	60mW@12Vin	5V@1.2A	86%@1.2A Vin=12V	Buck



L=36.5mm W=16.7mm H=12.8mm

Design Features

- Wide input voltage range from 10V to 32V
- Transparent input voltage surge 12V-40V-12V
- 4.75V-5.25V during input and load transients
- 5% output voltage accuracy
- 210kHz switching frequency
- Standby input current 5mA
- 1.2A ~1.4A accurate current limit
- Thermal shutdown protection
- Output cord compensation
- Over current protection
- Meet EN5502 EMC Standard

Operation and Application

ACT4515 is a wide input voltage, high efficiency Active CC step-down DC-DC converter that operates in either CV (Constant Output Voltage) mode or CC (Constant Output Current) mode. ACT4515 provides up to 1.5A output current at 210kHz switching frequency. Active CC is a patent-pending control scheme to provide CC function accuracy by sensorless constant current control, which eliminates the expensive, high accuracy current sense resistor, making it ideal for battery charging applications. charging applications. The ACT4515 operates at constant output voltage mode until it reaches the CC limit set by the ISET resistor. The devices are available in a SOP-8 package.

Key Component Selection

Higher output inductance reduces the inductor peak -to-peak current at the expense of higher larger core size and inductance DCR value. Usually, an optimum inductance value is selected to make its peak-to-peak current 20%-40% of the maximum load current. The Schottky diode must have current rating higher than the maximum output current and the reverse voltage rating higher than the maximum input voltage. Output capacitor is selected to keep the peak-to-peak voltage ripple under required value and also meet the load transient requirements. Usually, 22uFx2 ceramic capacitors are sufficient. In the case of tantalum or electrolytic types, 220uF capacitor is connected in parallel with a small 1µF-10uF ceramic capacitor to achieve small output voltage ripple and meet the requirements of input and load dynamic response.

USB

R7 22Ω C5 10nF/16V 1 L1 70µH HSB L2 42µH/1.5A 2 3 +Vin O 13 Bea U1 F1 3A R3 68k 7 5 ACT4515 C7 R8 SET 5k 1000pF/25V COMF open ZD3 本 6 4 6.2V ZD C1 C3 C2 2.2µF R1 R2 50V 20k oper oper 36\ 10µF 47µF LED1 C10 R6 C9 10pF 18.2k 50V 35V R5 🗖 D1 oper 20k 220pF 220µF 1µF 15k 47k B240A 25V 25V 10V 10V C6 4700pf 4 Bea GND O

Schematic of Charger

Figure 1:



ACT4515 5V/1.2A Smart Phone Car Charger

Bill of Materials

REF	DESCRIPTION	MFTR
F1	Fuse 3A,1206(Replaced by 0Ω 1206 chip resister)	Murata/TDK
L1	Choke Coil,75uH,DR=6x8mm, 1A, dip	ACT
L2	Choke Coil, ring core,42uH,8*4*4mm, 1.5A, dip	ACT
L3,4	Bead,K5B,T3.5x3x1.2mm	KingCore
D1	Schottky Diode, B240A, 40V/2A,SMB	Diodes
ZD1	Open	
ZD3	Open	
C1	Capacitor,Electrolytic,33uF/50V,Ф5x7mm,Dip	KSC
C2	Capacitor,Electrolytic,47uF/35V,Ф7.5x8mm,Dip	Koshin
C3	Ceramic capacitor, 2.2uF/50V, X7R, 1206	Murata/TDK
C4	Ceramic capacitor, 220pF/25V, X7R, 0603	Murata/TDK
C5	Ceramic capacitor, 10nF/16V, X7R, 0603	Murata/TDK
C6	Ceramic capacitor, 4700pF/25V, X7R, 0603	Murata/TDK
C7	Ceramic capacitor,1000pF/25V, X7R, 0603 (Open)	Murata/TDK
C8	Ceramic capacitor, 10pF/25, X7R, 0603	Murata/TDK
C9	Capacitor,Electrolytic,220uF/10V,Φ6.3x7.2mm,Dip	Micon
C10	Ceramic capacitor, 1uF/10V, X7R, 0603	Murata/TDK
R1	Chip Resistor, 20KΩ, 1/16W, 1%, 0603	Murata/TDK
R2	Open	
R3	Chip Resistor, 68KΩ, 1/16W, 1%, 0603	Murata/TDK
R4	Chip Resistor, 18.2KΩ, 1/16W, 1%, 0603	Murata/TDK
R5	Chip Resistor, 47KΩ, 1/16W, 1%, 0603	Murata/TDK
R6	Chip Resistor, 15KΩ, 1/16W ,5%, 0603	Murata/TDK
R7	Chip Resistor, 10Ω, 1/16W, 5%,0603	Murata/TDK
R8	Chip Resistor, 5KΩ, 1/16W, 5%,0805	Murata/TDK
U1	IC, ACT4515, SOP-8	ACT
LED	LED ,Green,0805	
USB	15mm*10mm*8mm	

PCB Top Layer



PCB Bottom Layer



PC Board Layout Guidance

1) Arrange the power components to reduce the AC loop size that consists of CIN, IN pin, SW pin the Schottky diode.

2) Place input decoupling ceramic capacitor CIN as close to IN pin as possible. CIN is connected power GND with vias or short and wide path.

3) Use copper plane for power GND for best heat dissipation and noise immunity.

4) Place feedback resistor close to FB pin.

5) Use short trace connecting HSB-C5-SW loop.

6) SW pad is a noisy node switching from Vin to GND. It should be isolated away from the rest of circuit for good EMI and low noise operation.

Typical performance characteristics







[<mark>///] <u>Active-Semi</u></mark>

ACT4513 5V/2.0A Smart Phone Car Charger

Input Voltage	Device	Standby Power	Output	Efficiency	Topology
10-32V	ACT4513	36mW@12Vin	5V@2.0A	84.4%@2.0A Vin=12V	Buck



L=32.7mm W=15.1mm H=12.8mm

Design Features

- Wide input voltage range from 10V to 32V
- Transparent input voltage surge up 12V-40V-12V
- 4.75V-5.25V during input and load transients
- 5% output voltage accuracy
- 210kHz switching frequency
- Standby input current 3mA
- 2.2A accurate current limit
- Shut down at output short circuit
- Thermal shutdown protection
- Output cord compensation
- Over current protection
- Pass radiated EMI test

Operation and Application

ACT4513 is a wide input voltage, high efficiency Active CC step-down DC-DC converter that operates in either CV (Constant Output Voltage) mode or CC (Constant Output Current) mode. ACT4513 provides up to 2.5A output current at 210kHz switching frequency. Active

Figure 1:

Schematic of Charger

CC function accuracy by senseless constant current control, which eliminates the expensive, high accuracy current sense resistor, making it ideal for battery charging applications. charging applications. The ACT4513 operates at constant output voltage mode until it reaches the CC limit set by the ISET resistor. The devices are available in a SOP8-EP package.

Key Component Selection

Higher output inductance reduces the inductor peak -to-peak current at the expense of higher larger core size and inductance DCR value. Usually, an optimum inductance value is selected to make its peak-to-peak current 20%-40% of the maximum load current. The Schottky diode must have current rating higher than the maximum output current and the reverse voltage rating higher than the maximum input voltage. Output capacitor is selected to keep the peak-to-peak voltage ripple under required value and also meet the load transient requirements. For this application, 22uFx2 ceramic capacitors are needed. In the case of tantalum or electrolytic types, 220uF capacitor is connected in parallel with a small 1µF-10uF ceramic capacitor to achieve small output voltage ripple and meet the requirements of input and load dynamic response.





ACT4513 5V/2.0A Smart Phone Car Charger

Bill of Materials

L1 Choke Coil,Dip, 6*8mm, phi=0.35mm, L=70-75uH ACT L2 Choke Coil,Dip, T8*4*4mm, phi=0.45mm, L=33uH ACT L3 Common Mode Choke, Dip, T6*4*3mm, phi=0.45mm, L=100uH ACT D1 Schottky Diode, B340A,40V/3A, SMA Diodes D2 Switch Diodes,1N4148WS, 0.2W, SOD323 Diodes ZD1 Zener Diode,GMZJ6:2A,6.2V,0.5W,Mini-Melf (open) Panjit ZD2 Zener Diode, BZT52C5V1S, 5.1V, 0.2W, SOD323 Diodes C1A Ceramic capacitor, 2.2uF/35V, X7R,0805 Murata/TD C1B Electroytic capacitor, 22uF/35V, X7R,0805 Murata/TD C2 Electroytic capacitor, 10uF/35V, X7R,0805 Murata/TD C2 Electroytic capacitor, 20uF/10V, 6.3x7mm Koshin C2A Ceramic capacitor, 10uF/10V, X7R,0805 Murata/TD C3 Ceramic capacitor, 0.01uF/16V, X7R,0603 Murata/TD C4 Ceramic capacitor, 470pF/25V, X7R, 0603 Murata/TD C5 Ceramic capacitor, 0.2uF/25V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 0.2uF/25V, X5R, 0603 Murata/TD C1 Ceipacic capacitor, 0.2uF/25V, X5	ĸ
L2 Choke Coil,Dip,T8*4*4mm, phi=0.45mm, L=33uH ACT L3 Common Mode Choke , Dip,T6*4*3mm, phi=0.45mm, L=100uH ACT D1 Schottky Diode, B340A,40V/3A, SMA Diodes D2 Switch Diodes,1N4148WS, 0.2W, SOD323 Diodes D2 Switch Diode, GMZJ6.2A,6.2V,0.5W, Mini-Melf (open) Panjit ZD1 Zener Diode, GMZJ6.2A,6.2V,0.5W, Mini-Melf (open) Panjit ZD2 Zener Diode, BZT52C5V1S, 5.1V, 0.2W, SOD323 Diodes C1A Ceramic capacitor, 2.2uF/35V, X7R,0805 Murata/TD C1B Electroytic capacitor, 40uF/35V, 6.3x7.8mm Koshin C1 Ceramic capacitor, 10uF/35V. X7R, 0805 Murata/TD C2 Electroytic capacitor, 20uF/10V, 6.3x7mm Koshin C3 Ceramic capacitor, 10uF/10V, X7R, 0805 Murata/TD C4 Ceramic capacitor, 400pF/10V, X7R, 0603 Murata/TD C5 Ceramic capacitor, 470pF/25V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 0.2uF/25V, X5R, 0603 Murata/TD C7 Ceramic capacitor, 0.2uF/25V, X5R, 0603 Murata/TD C6 Ceramic capacitor, 0.2uF/25V	ĸ
L3 Common Mode Choke ,Dip,T6*4*3mm, phi=0.45mm, L=100uH ACT D1 Schottky Diode, B340A,40V/3A, SMA Diodes D2 Switch Diodes,1N4148WS, 0.2W, SOD323 Diodes ZD1 Zener Diode, GMZJ6.2A,6.2V,0.5W, Mini-Melf (open) Panjit ZD2 Zener Diode, BZT52C5V1S, 5.1V, 0.2W, SOD323 Diodes C1A Ceramic capacitor, 2.2uF/35V, X7R,0805 Murata/TD C1B Electroytic capacitor, 47uF/35V, 6.3x7.8mm Koshin C1 Ceramic capacitor, 10uF/35V. X7R, 0805 Murata/TD C2 Electroytic capacitor, 220uF/10V,6.3x7mm Koshin C3 Ceramic capacitor, 10uF/10V, X7R,0805 Murata/TD C4 Ceramic capacitor, 400pF/10V, X7R, 0603 Murata/TD C4 Ceramic capacitor, 10uF/16V, X7R, 0603 Murata/TD C5 Ceramic capacitor, 1000pF/25V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 0.22uF/25V, X5R, 0603 Murata/TD C7 Ceramic capacitor, 1000pF/25V, X7R, 0603 Murata/TD F1 Fuse,3A,1206 (Replaced by 0Ω 1206 chip resistor) Murata/TD R1 Chip Resistor, 51KΩ, 1/	ĸ
D1 Schottky Diode, B340A,40V/3A, SMA Diodes D2 Switch Diodes,1N4148WS, 0.2W, SOD323 Diodes ZD1 Zener Diode,GMZJ6.2A,6.2V,0.5W,Mini-Melf (open) Panjit ZD2 Zener Diode, BZT52C5V1S, 5.1V, 0.2W, SOD323 Diodes C1A Ceramic capacitor, 2.2uF/35V, X7R,0805 Murata/TD C1B Electroytic capacitor, 47uF/35V, 6.3x7.8mm Koshin C1 Ceramic capacitor, 10uF/35V. X7R, 0805 Murata/TD C2 Electroytic capacitor, 10uF/16V, X7R,0805 Murata/TD C3 Ceramic capacitor, 0.01uF/16V, X7R,0603 Murata/TD C4 Ceramic capacitor, 10uF/10V, X7R,0603 Murata/TD C4 Ceramic capacitor, 10uF/10V, X7R,0603 Murata/TD C4 Ceramic capacitor, 4700F/10V, X7R, 0603 Murata/TD C5 Ceramic capacitor, 1000pF/25V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 0.22uF/25V, X5R, 0603 Murata/TD F1 Fuse,3A,1206 (Replaced by 0Ω 1206 chip resistor) Murata/TD R1 Chip Resistor, 51KΩ, 1/16W, 1%, 0603 Murata/TD R2 Chip Resistor, 9.76KΩ, 1/16W, 1%,	ĸ
D2 Switch Diodes,1N4148WS, 0.2W, SOD323 Diodes ZD1 Zener Diode,GMZJ6.2A,6.2V,0.5W,Mini-Melf (open) Panjit ZD2 Zener Diode, BZT52C5V1S, 5.1V, 0.2W, SOD323 Diodes C1A Ceramic capacitor, 2.2uF/35V, X7R,0805 Murata/TD C1B Electroytic capacitor, 4.2uF/35V, 6.3x7.8mm Koshin C1 Ceramic capacitor, 10uF/35V. X7R, 0805 Murata/TD C2 Electroytic capacitor, 220uF/10V, 6.3x7mm Koshin C2A Ceramic capacitor, 10uF/10V, X7R,0805 Murata/TD C3 Ceramic capacitor, 0.01uF/10V, X7R,0603 Murata/TD C4 Ceramic capacitor, 470pF/25V, X7R, 0603 Murata/TD C4 Ceramic capacitor, 470pF/25V, X7R, 0603 Murata/TD C5 Ceramic capacitor, 0.2uF/25V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 0.2uF/25V, X5R, 0603 Murata/TD F1 Fuse,3A,1206 (Replaced by 0Ω 1206 chip resistor) Murata/TD R1 Chip Resistor, 51KΩ, 1/16W, 1%, 0603 Murata/TD R2 Chip Resistor, 9.76KΩ, 1/16W, 1%, 0603 Murata/TD R3,R4 Chip Resistor, 11.6KΩ,	ĸ
ZD1 Zener Diode, GMZJ6:2A,6.2V,0.5W, Mini-Melf (open) Panjit ZD2 Zener Diode, BZT52C5V1S, 5.1V, 0.2W, SOD323 Diodes C1A Ceramic capacitor, 2.2uF/35V, X7R,0805 Murata/TD C1B Electroytic capacitor, 4.2uF/35V, K7R,0805 Murata/TD C1B Electroytic capacitor, 40uF/35V, K7R, 0805 Murata/TD C2 Electroytic capacitor, 20uF/10V, 6.3x7mm Koshin C2 Electroytic capacitor, 20uF/10V, 6.3x7mm Koshin C3 Ceramic capacitor, 10uF/10V, X7R,0805 Murata/TD C3 Ceramic capacitor, 0.01uF/16V, X7R,0603 Murata/TD C4 Ceramic capacitor, 4700F/10V, X7R, 0603 Murata/TD C5 Ceramic capacitor, 470pF/25V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 0.22uF/25V, X7R, 0603 Murata/TD C7 Ceramic capacitor, 0.22uF/25V, X5R, 0603 Murata/TD F1 Fuse,3A,1206 (Replaced by 0Ω 1206 chip resistor) Murata/TD R1 Chip Resistor, 51KΩ, 1/16W, 1%, 0603 Murata/TD R2 Chip Resistor, 9.76KΩ, 1/16W, 1%, 0603 Murata/TD R3,R4 Chip Resis	ĸ
ZD2 Zener Diode, BZT52C5V1S, 5.1V, 0.2W, SOD323 Diodes C1A Ceramic capacitor, 2.2uF/35V, X7R,0805 Murata/TD C1B Electroytic capacitor, 47uF/35V, 6.3x7.8mm Koshin C1 Ceramic capacitor, 10uF/35V, X7R, 0805 Murata/TD C2 Electroytic capacitor, 10uF/35V, X7R, 0805 Murata/TD C2 Electroytic capacitor, 220uF/10V, 6.3x7mm Koshin C2 Electroytic capacitor, 200uF/10V, X7R,0805 Murata/TD C3 Ceramic capacitor, 0.01uF/16V, X7R,0603 Murata/TD C4 Ceramic capacitor, 400pF/10V, X7R, 0603 Murata/TD C5 Ceramic capacitor, 1000pF/25V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 0.22uF/25V, X7R, 0603 Murata/TD C7 Ceramic capacitor, 0.22uF/25V, X7R, 0603 Murata/TD F1 Fuse,3A,1206 (Replaced by 0Ω 1206 chip resistor) Murata/TD R1 Chip Resistor, 51KΩ, 1/16W, 1%, 0603 Murata/TD R2 Chip Resistor, 9.76KΩ, 1/16W, 1%, 0603 Murata/TD R3,R4 Chip Resistor, 11.6KΩ, 1/16W, 5%, 0603 Murata/TD R5 Chip Resistor, 1	ĸ
C1A Ceramic capacitor, 2.2uF/35V, X7R,0805 Murata/TD C1B Electroytic capacitor, 47uF/35V, 6.3x7.8mm Koshin C1 Ceramic capacitor, 10uF/35V, X7R, 0805 Murata/TD C2 Electroytic capacitor, 22uF/10V, 6.3x7mm Koshin C2 Electroytic capacitor, 22uF/10V, 6.3x7mm Koshin C2 Electroytic capacitor, 10uF/16V, X7R,0805 Murata/TD C3 Ceramic capacitor, 0.01uF/16V, X7R,0603 Murata/TD C4 Ceramic capacitor, 4700F/10V, X7R, 0603 Murata/TD C5 Ceramic capacitor, 1000F/25V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 1000F/25V, X7R, 0603 Murata/TD C7 Ceramic capacitor, 0.22uF/25V, X5R, 0603 Murata/TD F1 Fuse,3A,1206 (Replaced by 0Ω 1206 chip resistor) Murata/TD R1 Chip Resistor, 51KΩ, 1/16W, 1%, 0603 Murata/TD R2 Chip Resistor, 9.76KΩ, 1/16W, 1%, 0603 Murata/TD R3,R4 Chip Resistor, 11.6KΩ, 1/16W, 1%, 0603 Murata/TD R5 Chip Resistor, 11.6KΩ, 1/16W, 1%, 0603 Murata/TD	K K
C1B Electroytic capacitor,47uF/35V,6.3x7.8mm Koshin C1 Ceramic capacitor, 10uF/35V. X7R, 0805 Murata/TD C2 Electroytic capacitor, 220uF/10V,6.3x7mm Koshin C2 Electroytic capacitor, 20uF/10V, 6.3x7mm Koshin C2 Electroytic capacitor, 20uF/10V, X7R,0805 Murata/TD C3 Ceramic capacitor, 0.01uF/16V, X7R,0603 Murata/TD C4 Ceramic capacitor, 4700F/10V, X7R, 0603 Murata/TD C5 Ceramic capacitor, 100pF/25V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 0.22uF/25V, X7R, 0603 Murata/TD C7 Ceramic capacitor, 0.22uF/25V, X5R, 0603 Murata/TD F1 Fuse,3A,1206 (Replaced by 0Ω 1206 chip resistor) Murata/TD R1 Chip Resistor, 51KΩ, 1/16W, 1%, 0603 Murata/TD R2 Chip Resistor, 9.76KΩ, 1/16W, 1%, 0603 Murata/TD R3,R4 Chip Resistor, 11.6KΩ, 1/16W, 1%, 0603 Murata/TD R5 Chip Resistor, 11.6KΩ, 1/16W, 1%, 0603 Murata/TD	к
C1 Ceramic capacitor, 10uF/35V. X7R, 0805 Murata/TD C2 Electroytic capacitor, 220uF/10V, 6.3x7mm Koshin C2A Ceramic capacitor, 10uF/10V, X7R, 0805 Murata/TD C3 Ceramic capacitor, 0.01uF/10V, X7R, 0803 Murata/TD C4 Ceramic capacitor, 4700F/10V, X7R, 0603 Murata/TD C5 Ceramic capacitor, 47pF/25V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 1000pF/25V, X7R, 0603 Murata/TD C7 Ceramic capacitor, 0.22uF/25V, X7R, 0603 Murata/TD F1 Fuse, 3A, 1206 (Replaced by 0Ω 1206 chip resistor) Murata/TD R1 Chip Resistor, 51KΩ, 1/16W, 1%, 0603 Murata/TD R2 Chip Resistor, 9.76KΩ, 1/16W, 1%, 0603 Murata/TD R3,R4 Chip Resistor, 11.6KΩ, 1/16W, 1%, 0603 Murata/TD R5 Chip Resistor, 11.6KΩ, 1/16W, 1%, 0603 Murata/TD	к
C2 Electroytic capacitor,220uF/10V,6.3x7mm Koshin C2A Ceramic capacitor,10uF/10V,X7R,0805 Murata/TD C3 Ceramic capacitor, 0.01uF/16V, X7R,0603 Murata/TD C4 Ceramic capacitor,4700pF/10V, X7R,0603 Murata/TD C5 Ceramic capacitor,4700pF/10V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 47pF/25V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 1000pF/25V, X7R, 0603 Murata/TD C7 Ceramic capacitor, 0.22uF/25V, X5R, 0603 Murata/TD F1 Fuse,3A,1206 (Replaced by 0Ω 1206 chip resistor) Murata/TD R1 Chip Resistor, 51KΩ, 1/16W, 1%, 0603 Murata/TD R2 Chip Resistor, 9.76KΩ, 1/16W, 1%, 0603 Murata/TD R3,R4 Chip Resistor, 11.6KΩ, 1/16W, 1%, 0603 Murata/TD R5 Chip Resistor, 11.6KΩ, 1/16W, 1%, 0603 Murata/TD	
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C3 Ceramic capacitor, 0.01uF/16V, X7R,0603 Murata/TD C4 Ceramic capacitor,4700pF/10V, X7R, 0603 Murata/TD C5 Ceramic capacitor,4700pF/10V, X7R, 0603 Murata/TD C6 Ceramic capacitor,47pF/25V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 1000pF/25V, X7R, 0603 Murata/TD C7 Ceramic capacitor, 0.22uF/25V, X5R, 0603 Murata/TD F1 Fuse,3A, 1206 (Replaced by 0Ω 1206 chip resistor) Murata/TD R1 Chip Resistor, 51KΩ, 1/16W, 1%, 0603 Murata/TD R2 Chip Resistor, 9.76KΩ, 1/16W, 1%, 0603 Murata/TD R3,R4 Chip Resistor, 11.6KΩ, 1/16W, 5%, 0603 Murata/TD R5 Chip Resistor, 11.6KΩ, 1/16W, 1%, 0603 Murata/TD	к
C4 Ceramic capacitor,4700pF/10V, X7R, 0603 Murata/TD C5 Ceramic capacitor,4700pF/10V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 47pF/25V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 1000pF/25V, X7R, 0603 Murata/TD C7 Ceramic capacitor, 0.22uF/25V, X5R, 0603 Murata/TD F1 Fuse,3A,1206 (Replaced by 0Ω 1206 chip resistor) Murata/TD R1 Chip Resistor, 51KΩ, 1/16W, 1%, 0603 Murata/TD R2 Chip Resistor, 9.76KΩ, 1/16W, 1%, 0603 Murata/TD R3,R4 Chip Resistor, 4.7KΩ, 1/16W, 5%, 0603 Murata/TD R5 Chip Resistor, 11.6KΩ, 1/16W, 1%, 0603 Murata/TD	к
C5 Ceramic capacitor, 47pF/25V, X7R, 0603 Murata/TD C6 Ceramic capacitor, 1000pF/25V, X7R, 0603 Murata/TD C7 Ceramic capacitor, 0.22uF/25V, X5R, 0603 Murata/TD F1 Fuse,3A,1206 (Replaced by 0Ω 1206 chip resistor) Murata/TD R1 Chip Resistor, 51KΩ, 1/16W, 1%, 0603 Murata/TD R2 Chip Resistor, 9.76KΩ, 1/16W, 1%, 0603 Murata/TD R3,R4 Chip Resistor, 11.6KΩ, 1/16W, 1%, 0603 Murata/TD R5 Chip Resistor, 11.6KΩ, 1/16W, 1%, 0603 Murata/TD	к
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C7 Ceramic capacitor, 0.22uF/25V, X5R, 0603 Murata/TD F1 Fuse,3A,1206 (Replaced by 0Ω 1206 chip resistor) Murata/TD R1 Chip Resistor, 51KΩ, 1/16W, 1%, 0603 Murata/TD R2 Chip Resistor, 9.76KΩ, 1/16W, 1%, 0603 Murata/TD R3,R4 Chip Resistor, 4.7KΩ, 1/16W, 5%, 0603 Murata/TD R5 Chip Resistor, 11.6KΩ, 1/16W, 1%, 0603 Murata/TD	к
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R1 Chip Resistor, 51KΩ, 1/16W, 1%, 0603 Murata/TD R2 Chip Resistor, 9.76KΩ, 1/16W, 1%, 0603 Murata/TD R3,R4 Chip Resistor, 4.7KΩ, 1/16W, 5%, 0603 Murata/TD R5 Chip Resistor, 11.6KΩ, 1/16W, 1%, 0603 Murata/TD	к
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R5 Chip Resistor, 11.6KΩ, 1/16W, 1%, 0603 Murata/TD	к
	к
R7 Chip Resistor, 22Ω, 1/16W, 1%, 0603 Murata/TD	к
R8 Chip Resistor, 2KΩ, 1/16W ,5%,0603 Murata/TD	к
R10 Chip Resistor, 100KΩ, 1/16W ,5%,0603 Murata/TD	к
R11 Chip Resistor, 75KΩ, 1/16W ,5%,0603 Murata/TD	к
R13 Chip Resistor, 43.2KΩ, 1/16W ,5%,0603 Murata/TD	к
R12,R14 Chip Resistor, 49.9KΩ, 1/16W ,5%,0603 Murata/TD	к
U1 IC, ACT4513,SOP-8-EP ACT	
USB USB Rev:A	
LED ,White,Dip	

PCB Top Layer



PCB Bottom Layer



PC Board Layout Guidance

1) Arrange the power components to reduce the AC loop size that consists of CIN, IN pin, SW pin the Schottky diode.

2) Place input decoupling ceramic capacitor CIN as close to IN pin as possible. CIN is connected power GND with vias or short and wide path.

3) Use copper plane for power GND for best heat dissipation and noise immunity.

4) Place feedback resistor close to FB pin.

5) Use short trace connecting HSB-C3-SW loop. Thermal pad is connected to a large ground copper area.

6) SW pad is a noisy node switching from Vin to GND. It should be isolated away from the rest of circuit for good

Typical performance characteristics



Radiated EMI Test



EN 55022 RE 3 m QP(Class B).LimitLine
 Data Reduction Result 1[1]

80 100M

ŝò

0+ 30M

EVALUATION KITS	Vin	Vo	lo
Car Charger ACT4513- DMB-#1	10-32V	4.75-5.25V	2000mA

Frequency in Hz

00 400 50

800 10



ACT4523 5V/2.1A iPAD Car Charger

Input Voltage	Device	Standby Power	Output	Efficiency	Topology
10-32V	ACT4523	39mW@12Vin	5V@2.1A	87%@2.1A Vin=12V	Buck



L=39.8mm W=14.9mm H=12.6mm

Design Features

- Wide input voltage range from 10V to 32V
- Transparent input voltage surge 12V-40V-12V
- + 4.75V-5.25V during input and load transients
- 5% output voltage accuracy
- 225kHz switching frequency
- Standby input current 3.2mA
- 2.35A accurate current limit
- Shut down at output short circuit
- Thermal shutdown protection
- Output cord compensation
- Over current protection
- Meet the EN55022 EMC standard

Operation and Application

ACT4523 is a wide input voltage, high efficiency Active CC step-down DC-DC converter that operates in either CV (Constant Output Voltage) mode or CC (Constant Output Current) mode. ACT4523 provides up to 3.0A output current at 225kHz switching frequency. Active CC is a patent-pending control scheme to

Figure 1:



Schematic of Charger

provide CC function accuracy by senseless constant current control, which eliminates the expensive, high accuracy current sense resistor, making it ideal for battery charging applications. charging applications. The ACT4523 operates at constant output voltage mode until it reaches the CC limit set by the ISET resistor. The devices are available in a SOP8-EP package.

Key Component Selection

Higher output inductance reduces the inductor peak -to-peak current at the expense of higher larger core size and inductance DCR value. Usually, an optimum inductance value is selected to make its peak-to-peak current 20%-40% of the maximum load current. The Schottky diode must have current rating higher than the maximum output current and the reverse voltage rating higher than the maximum input voltage. Output capacitor is selected to keep the peak-to-peak voltage ripple under required value and also meet the load transient requirements. For this application, 22uFx2 ceramic capacitors are needed. In the case of tantalum or electrolytic types, 220uF capacitor is connected in parallel with a small 1µF-10uF ceramic capacitor to achieve small output voltage ripple and meet the requirements of input and load dynamic response



ACT4523 5V/2.1A iPAD Car Charger

Bill of Materials

REF	DESCRIPTION	MFTR
L1	Choke Coil,Dip, 6*8mm, phi=0.35mm, L=70-75uH	ACT
L2	Choke Coil,Dip,T8*5*4mm, phi=0.45mm, L=33uH	ACT
L3	Common Mode Choke ,Dip,T6*3*3mm, phi=0.45mm, L=100uH	ACT
D1	Schottky Diode, B340A,40V/3A, SMA	Diodes
D2	Switch Diode,1N4148WS, 0.2W, SOD323	Diodes
ZD1	Zener Diode,GMZJ6.2A,6.2V,0.5W,Mini-Melf (open)	Panjit
ZD2	Zener Diode,BZT52C5V1S, 5.1V, 0.2W, SOD323	Diodes
C1A	Electroytic capacitor,100uF/35V,6.3x11.5mm	Koshin
C1B	Ceramic capacitor,2.2uF/50V,0805	Murata/TDK
C1	Electroytic capacitor,33uF/50V,5x7mm	Koshin
C2	Electroytic capacitor,220uF/10V,6.3x7mm	Koshin
C2A	Ceramic capacitor, 10uF/10V, X7R,0805	Murata/TDK
C01	Ceramic capacitor, 10uF/35V, X7R,1206	Murata/TDK
C3	Ceramic capacitor, 0.01uF/25V, X7R,0603	Murata/TDK
C4	Ceramic capacitor,4700pF/10V, X7R, 0603	Murata/TDK
C5	Ceramic capacitor, 47pF/25V, X7R, 0603	Murata/TDK
C6	Ceramic capacitor, 1000pF/25V, X7R, 0603	Murata/TDK
C7	Ceramic capacitor, 2.2uF/25V, X5R, 0603	Murata/TDK
F1	Fuse,3A,1206 (Replaced by 0Ω 1206 chip resistor)	Murata/TDK
R1	Chip Resistor, 51KΩ, 1/16W, 1%, 0603	Murata/TDK
R2	Chip Resistor, 9.76KΩ, 1/16W, 1%, 0603	Murata/TDK
R3,R4	Chip Resistor, 4.7KΩ, 1/16W, 5%, 0603	Murata/TDK
R5	Chip Resistor, 11.5KΩ, 1/16W, 1%, 0603	Murata/TDK
R7	Chip Resistor, 22Ω, 1/16W, 1%, 0603	Murata/TDK
R8	Chip Resistor, 3KΩ, 1/16W ,5%,0603	Murata/TDK
R10	Chip Resistor, 100KΩ, 1/16W ,5%,0603	Murata/TDK
R11	Chip Resistor, 75KΩ, 1/16W ,5%,0603	Murata/TDK
R13	Chip Resistor, 43.2KΩ, 1/16W ,5%,0603	Murata/TDK
R12,R14	Chip Resistor, 49.9KΩ, 1/16W ,5%,0603	Murata/TDK
U1	IC, ACT4523,SOP-8-EP	ACT
USB	USB Rev:A	
LED	LED ,White,Dip	

PCB Top Layer



PCB Bottom Layer



PC Board Layout Guidance

1) Arrange the power components to reduce the AC loop size that consists of CIN, IN pin, SW pin the Schottky diode.

2) Place input decoupling ceramic capacitor CIN as close to IN pin as possible. CIN is connected power GND with vias or short and wide path.

3) Use copper plane for power GND for best heat dissipation and noise immunity.

4) Place feedback resistor close to FB pin.

5) Use short trace connecting HSB-C3-R7-SW loop.

Thermal pad is connected to a large ground copper area.

6) SW pad is a noisy node switching from Vin to GND. It should be isolated away from the rest of circuit for good EMI and low noise operation.

Typical performance characteristics





_	EN 55022 RE 3 m QP(Class B) LimitLine	
ŧ-	Data Reduction Result 1 [1]	

EVALUATION KITS	Vin	Vo	lo
Car Charger ACT4523- DMB-#2	10-32V	4.75-5.25V	2100mA



ACT4455—5V/3.1A Dual-Output Car Charger

Input Voltage	Device	Standby Power	Output	Efficiency
7.5-33V	ACT4455	150mW@12Vin	5V@2.1+1A	90%@3.1A,Vin=12V



L=59mm W=20.2mm H=18mm

Design Features

- Wide input voltage range from 7.5V to 33V
- Transparent input voltage surge 12V-40V-12V
- 4.75V-5.25V during input and load transients
- 5% output voltage accuracy
- 200kHz switching frequency
- Standby input current 10mA
- Programmable precise output current limit via sensing resistance
- 3ms internal soft startup time
- Cycle-by-cycle over current protection
- Thermal shutdown protection
- Output cord compensation
- · Nearly zero power loss at over loading or output short
- Hiccup mode at output over voltage
- Auto recovery into full load after faults
- Meet EN5502 EMC standard

Figure 1:

Key Component Selection

Higher output inductance reduces the inductor peak -to-peak current at the expense of higher larger core size and inductance DCR value. Usually, an optimum inductance value is selected to make its peak-to-peak current 20%-40% of the maximum load current. The Schottky diode must have current rating higher than the maximum output current and the reverse voltage rating.

higher than the maximum input voltage. Double schottky diodes could be added to achieve higher efficiency and pass single fault test. Output capacitor is selected to keep the peak-to-peak voltage ripple under required value and also meet the load transient requirements. In the case of tantalum or electrolytic types, 680uF capacitor is connected in parallel with a small 1μ F-10uF ceramic capacitor to achieve small output voltage ripple and meet the requirements of input and load dynamic response.

Schematic of 5V/3.1A Dual-Output Car Charger





ACT4455-5V/3.1A Dual-Output Car Charger

Bill of Materials

REF	DESCRIPTION	MFTR
L1	Choke Coil, 6*3*3mm L=150uH, dip	ACT
L2	Choke Coil, ring core,25uH,11*6.5*4mm, 5A, dip	ACT
L3	Choke Coil, 9*6*5mm L=100uH, dip	ACT
D1	Schottky Diode, SSC54, 40V/5A, SMC	Vishay
ZD1	Open	
ZD2	Zener Diode, 6.1V/0.2W	Diodes
C1	Capacitor, Electrolytic, 47uF/35V, Ф6.3x8mm, 105°C	KSC
C2	Capacitor, Electrolytic, 100uF/35V, Ф6.3x11.5mm, 105°C	Koshin
C3	capacitor, Electrolytic,680uF/10V, Ф8x11.5mm,105°C	Koshin
C4	Ceramic capacitor, 2.2uF/35V, X7R, 0805	Murata/TDK
C5	Ceramic capacitor, 10uF/35V, X7R, 1206	Murata/TDK
C6	Ceramic capacitor, 4.7nF/25V, X7R, 0402	Murata/TDK
C7	Ceramic capacitor,100pF/25V, X7R, 0402	Murata/TDK
C8	Ceramic capacitor, 22nF/25V, X7R, 0603	Murata/TDK
C9	Ceramic capacitor. 2.2nF/25V.X7R.0603	Murata/TDK
C10	Optional	Murata/TDK
C11	Ceramic capacitor, 2.2nF/25V, X7R, 0805	Murata/TDK
C12	Ceramic capacitor, 2.2uF/10V, X7R, 0805	Murata/TDK
C13,C14	Ceramic capacitor, 1uF/16V, X7R, 0603	Murata/TDK
Rcs1	Chip Resistor, 50mΩ,1/2W, 1%, 1206	ROHM
Rcs2	Chip Resistor, 100mΩ,1W, 1%, 1210	Vishay
R3	Chip Resistor, 51KΩ,1/16W, 1%, 0603	Murata/TDK
R4	Chip Resistor, 9.76KΩ,1/16W, 1%, 0603	Murata/TDK
R5	Chip Resistor, 0Ω,1/16W, 5%, 0603	Murata/TDK
R6	Chip Resistor, 15KΩ,1/16W ,5%, 0603	Murata/TDK
R7	Chip Resistor, 5.1Ω,1/4W, 5%,1206	Murata/TDK
R8	Chip Resistor, 2KΩ,1/10W, 1%,0603	Murata/TDK
R9,R10	Optional	
R11,R12	Chip Resistor, 1KΩ,1/10W, 1%,0603	Murata/TDK
R13	Chip Resistor, 1KΩ,1/10W, 5%,0603	Murata/TDK
R14,R20	Chip Resistor, 75KΩ,1/10W, 1%,0603	Murata/TDK
R15,R17,R19 ,R21	Chip Resistor, 49.9KΩ,1/10W, 1%,0603	Murata/TDK
R16,R18	Chip Resistor, 43.2KΩ,1/10W, 1%,0603	Murata/TDK
U1	IC, ACT4455, SOP-8 EP	ACT
LED		
	LED ,Red,0805	

PCB Top Layer



PCB Bottom Layer



PC Board Layout Guidance

1) Arrange the power components to reduce the AC loop size that consists of CIN, IN pin, SW pin the Schottky diode.

2) Place input decoupling ceramic capacitor CIN as close to IN pin as possible. CIN is connected power GND with vias or short and wide path.

3) Use copper plane for power GND for best heat dissipation and noise immunity.

4) Place feedback resistor close to FB pin.

5) Use short trace connecting HSB-R5-C7-SW loop.

6) SW pad is a noisy node switching from Vin to GND. It should be isolated away from the rest of circuit for good EMI and low noise operation.

7) Thermal pad is connected to GND layer through at least 6 vias.

Typical performance characteristics







ACT4455—5V/4.2A Dual-Output Car Charger

Input Voltage	Device	Standby Power	Output	Efficiency
7.5-33V	ACT4455	150mW@12Vin	5V@2.1+2.1A	88%@4.2A Vin=12V



L=63mm W=23.5mm H=18mm

Design Features

- Wide input voltage range from 7.5V to 33V
- Transparent input voltage surge 12V-40V-12V
- 4.75V-5.25V during input and load transients
- 5% output voltage accuracy
- 200kHz switching frequency
- Standby input current 10mA
- Programmable precise output current limit via sensing resistors
- 3ms internal soft startup time
- Cycle-by-cycle over current protection
- Thermal shutdown protection
- Output cord compensation
- · Nearly zero power loss at over loading or output short
- Hiccup mode at output over voltage
- Auto recovery into full load after faults
- Meet EN5502 EMC Standard

Figure 1:

Key Component Selection

Higher output inductance reduces the inductor peak -to-peak current at the expense of higher larger core size and inductance DCR value. Usually, an optimum inductance value is selected to make its peak-to-peak current 20%-40% of the maximum load current. The Schottky diode must have current rating higher than the maximum output current and the reverse voltage rating.

higher than the maximum input voltage. Double schottky diodes could be added to achieve higher efficiency and pass single fault test. Output capacitor is selected to keep the peak-to-peak voltage ripple under required value and also meet the load transient requirements. In the case of tantalum or electrolytic types, 680uF capacitor is connected in parallel with a small 1µF -10uF ceramic capacitor to achieve small output voltage ripple and meet the requirements of input and load dynamic response.



Schematic of 5V/4.2A Dual-Output Car Charger



ACT4455-5V/4.2A Dual-Output Car Charger

Bill of Materials

L1 Choke Coil, 6*3*3mm L=150uH, dip ACT L2 Choke Coil, ring core, 18uH, 11*6.5*4mm, 5A, dip ACT L3 Choke Coil, 9*6*5mm L=100uH, dip ACT D1 Schottky Diode, V10PL45-EH 45V/10A, SMPC Vishay ZD1 Open ZD2 Zener Diode, 6.1V/0.2W Diodes C1 Capacitor,Electrolytic,47uF/35V,Φ6.3x8mm,105°C KSC C2 Capacitor,Electrolytic,680uF/10V, Φ8.11.5mm,105°C Koshir C3 capacitor, Electrolytic,680uF/10V, Φ8.11.5mm,105°C Koshir C4 Ceramic capacitor, 2.2uF/35V, X7R, 0805 Murata/T C5 Ceramic capacitor, 10uF/35V, X7R, 1206 Murata/T C6 Ceramic capacitor, 100F/25V, X7R, 0402 Murata/T C7 Ceramic capacitor, 2.2uF/25V, X7R, 0402 Murata/T C6 Ceramic capacitor, 2.2uF/25V, X7R, 0402 Murata/T C6 Ceramic capacitor, 2.2uF/25V, X7R, 0402 Murata/T C7 Ceramic capacitor, 2.2uF/25V, X7R, 0403 Murata/T
L2 Choke Coil, ring core, 18uH, 11*6.5*4mm, 5A, dip ACT L3 Choke Coil, 9*6*5mm L=100uH, dip ACT D1 Schotky Diode, V10PL45-EH 45V/10A, SMPC Vishay ZD1 Open Zener Diode, 6.1V/0.2W Diodes C1 Capacitor,Electrolytic,47uF/35V,Φ6.3x8mm,105°C KSC C2 Capacitor,Electrolytic,100uF/35V,Φ6.3x11.5mm,105°C Koshir C3 capacitor, Electrolytic,680uF/10V, Φ8x11.5mm,105°C Koshir C4 Ceramic capacitor, 2.2uF/35V, X7R, 0805 Murata/T C5 Ceramic capacitor, 10uF/35V, 7R, 1206 Murata/T C6 Ceramic capacitor, 10uF/25V, X7R, 0402 Murata/T C6 Ceramic capacitor, 100F/25V, X7R, 0402 Murata/T C7 Ceramic capacitor, 22nF/25V, X7R, 0402 Murata/T C7 Ceramic capacitor, 22nF/25V, X7R, 0402 Murata/T C6 Murata/T
L3 Choke Coil, 9°6°5mm L=100uH, dip ACT D1 Schottky Diode, V10PL45-EH 45V/10A, SMPC Vishay ZD1 Open Z ZD2 Zener Diode, 6.1V/0.2W Diodes C1 Capacitor,Electrolytic,47uF/35V,Φ6.3x8mm,105°C KSC C2 Capacitor,Electrolytic,100uF/35V,Φ6.3x11.5mm,105°C Koshir C3 capacitor, Electrolytic,680uF/10V, Φ8x11.5mm,105°C Koshir C4 Ceramic capacitor, 2.2uF/35V, X7R, 0805 Murata/T C5 Ceramic capacitor, 10uF/35V, V7R, 1206 Murata/T C6 Ceramic capacitor, 4.7nF/25V, X7R, 0402 Murata/T C7 Ceramic capacitor, 22nF/25V, X7R, 0402 Murata/T C8 Ceramic capacitor, 22nF/25V, X7R, 0603 Murata/T
D1 Schottky Diode, V10PL45-EH 45V/10A, SMPC Vishay ZD1 Open ZD2 Zener Diode, 6.1V/0.2W Diodes C1 Capacitor,Electrolytic,47uF/35V,Φ6.3x8mm,105°C KSC C2 Capacitor,Electrolytic,100uF/35V,Φ6.3x11.5mm,105°C Koshir C3 capacitor,Electrolytic,680uF/10V, Φ8x11.5mm,105°C Koshir C4 Ceramic capacitor, 2.2uF/35V, X7R, 0805 Murata/T C5 Ceramic capacitor, 10uF/35V, X7R, 1206 Murata/T C6 Ceramic capacitor, 4.7nF/25V, X7R, 0402 Murata/T C7 Ceramic capacitor, 22pF/25V, X7R, 0603 Murata/T C8 Ceramic capacitor, 22pF/25V, X7R, 0603 Murata/T
ZD1 Open ZD2 Zener Diode, 6.1V/0.2W Diodes C1 Capacitor,Electrolytic,47uF/35V,Φ6.3x8mm,105°C KSC C2 Capacitor,Electrolytic,100uF/35V,Φ6.3x11.5mm,105°C Koshir C3 capacitor,Electrolytic,680uF/10V, Φ8x11.5mm,105°C Koshir C4 Ceramic capacitor, 2.2uF/35V, X7R, 0805 Murata/T C5 Ceramic capacitor, 10uF/35V, X7R, 1206 Murata/T C6 Ceramic capacitor, 4.7nF/25V, X7R, 0402 Murata/T C7 Ceramic capacitor, 20pF/25V, X7R, 0402 Murata/T C8 Ceramic capacitor, 20pF/25V, X7R, 0603 Murata/T
ZD2 Zener Diode, 6.1V/0.2W Diodes C1 Capacitor, Electrolytic, 47uF/35V, Φ6.3x8mm, 105°C KSC C2 Capacitor, Electrolytic, 100uF/35V, Φ6.3x11.5mm, 105°C Koshir C3 capacitor, Electrolytic, 680uF/10V, Φ8x11.5mm, 105°C Koshir C4 Ceramic capacitor, 2.2uF/35V, X7R, 0805 Murata/T C5 Ceramic capacitor, 10uF/35V, X7R, 1206 Murata/T C6 Ceramic capacitor, 4.7nF/25V, X7R, 0402 Murata/T C7 Ceramic capacitor, 100pF/25V, X7R, 0402 Murata/T C8 Ceramic capacitor, 22nF/25V, X7R, 0603 Murata/T
C1 Capacitor,Electrolytic,47uF/35V,Φ6.3x8mm,105°C KSC C2 Capacitor,Electrolytic,100uF/35V,Φ6.3x11.5mm,105°C Koshir C3 capacitor,Electrolytic,680uF/10V, Φ8x11.5mm,105°C Koshir C4 Ceramic capacitor, 2.2uF/35V, X7R, 0805 Murata/T C5 Ceramic capacitor, 10uF/35V, X7R, 1206 Murata/T C6 Ceramic capacitor, 4.7nF/25V, X7R, 0402 Murata/T C7 Ceramic capacitor, 20pF/25V, X7R, 0402 Murata/T C8 Ceramic capacitor, 20pF/25V, X7R, 0603 Murata/T
C2 Capacitor, Electrolytic, 100uF/35V, Φ6.3x11.5mm, 105°C Koshir C3 capacitor, Electrolytic, 680uF/10V, Φ8x11.5mm, 105°C Koshir C4 Ceramic capacitor, 2.2uF/35V, X7R, 0805 Murata/T C5 Ceramic capacitor, 10uF/35V, X7R, 1206 Murata/T C6 Ceramic capacitor, 4.7nF/25V, X7R, 0402 Murata/T C7 Ceramic capacitor, 10uF/25V, X7R, 0402 Murata/T C8 Ceramic capacitor, 22nF/25V, X7R, 0603 Murata/T
C3 capacitor, Electrolytic,680uF/10V, Φ8x11.5mm,105°C Koshir C4 Ceramic capacitor, 2.2uF/35V, X7R, 0805 Murata/T C5 Ceramic capacitor, 10uF/35V, X7R, 1206 Murata/T C6 Ceramic capacitor, 4.7nF/25V, X7R, 0402 Murata/T C7 Ceramic capacitor, 100pF/25V, X7R, 0402 Murata/T C8 Ceramic capacitor, 22nF/25V, X7R, 0603 Murata/T
C4 Ceramic capacitor, 2.2uF/35V, X7R, 0805 Murata/T C5 Ceramic capacitor, 10uF/35V, X7R, 1206 Murata/T C6 Ceramic capacitor, 4.7nF/25V, X7R, 0402 Murata/T C7 Ceramic capacitor, 100pF/25V, X7R, 0402 Murata/T C8 Ceramic capacitor, 22nF/25V, X7R, 0603 Murata/T
C5 Ceramic capacitor, 10uF/35V, X7R, 1206 Murata/T C6 Ceramic capacitor, 4.7nF/25V, X7R, 0402 Murata/T C7 Ceramic capacitor, 100pF/25V, X7R, 0402 Murata/T C8 Ceramic capacitor, 22nF/25V, X7R, 0603 Murata/T
C6 Ceramic capacitor, 4.7nF/25V, X7R, 0402 Murata/T C7 Ceramic capacitor, 100pF/25V, X7R, 0402 Murata/T C8 Ceramic capacitor, 22nF/25V, X7R, 0603 Murata/T
C7 Ceramic capacitor,100pF/25V, X7R, 0402 Murata/T C8 Ceramic capacitor, 22nF/25V, X7R, 0603 Murata/T
C8 Ceramic capacitor, 22nF/25V, X7R, 0603 Murata/T
C9 Ceramic capacitor. 2.2nF/25V.X7R. 0603 Murata/T
C10 Optional Murata/T
C11 Ceramic capacitor, 2.2nF/25V, X7R, 0805 Murata/T
C12 Ceramic capacitor, 2.2uF/10V, X7R, 0805 Murata/T
C13,C14 Ceramic capacitor, 1uF/16V, X7R, 0603 Murata/T
Rcs1,Rcs2 Chip Resistor, 50mΩ,1/2W, 1%, 1210 ROHM
R1A,R2A Optional
R3 Chip Resistor, 51KΩ,1/16W, 1%, 0603 Murata/T
R4 Chip Resistor, 9.76KΩ,1/16W, 1%, 0603 Murata/T
R5 Chip Resistor, 0Ω,1/16W, 5%, 0603 Murata/T
R6 Chip Resistor, 15KΩ,1/16W ,5%, 0603 Murata/T
R7 Chip Resistor, 5.1Ω,1/4W, 5%,1206 Murata/T
R8 Chip Resistor, 2KΩ,1/10W, 1%,0603 Murata/T
R9,R10 Optional
R11,R12 Chip Resistor, 1KΩ,1/10W, 1%,0603 Murata/T
R13 Chip Resistor, 1KΩ,1/10W, 5%,0603 Murata/T
R14,R18 Chip Resistor, 75KΩ,1/10W, 1%,0603 Murata/T
R15,R17,R19 ,R21 Chip Resistor, 49.9KΩ,1/10W, 1%,0603 Murata/T
R16,R20 Chip Resistor, 43.2KΩ,1/10W, 1%,0603 Murata/T
U1 IC, ACT4455, SOP-8 EP ACT
LED LED ,Red,0805
USB 17.5mm*14.5mm*15.7mm

PCB Top Layer



PCB Bottom Layer



PC Board Layout Guidance

1) Arrange the power components to reduce the AC loop size that consists of CIN, IN pin, SW pin the Schottky diode.

2) Place input decoupling ceramic capacitor CIN as close to IN pin as possible. CIN is connected power GND with vias or short and wide path.

3) Use copper plane for power GND for best heat dissipation and noise immunity.

4) Place feedback resistor close to FB pin.

5) Use short trace connecting HSB-R5-C7-SW loop.

6) SW pad is a noisy node switching from Vin to GND.

It should be isolated away from the rest of circuit for good EMI and low noise operation.

7) Thermal pad is connected to GND layer through at least 6 vias.





Radiated EMI Test



Site : chamber Condition : CISPR CLASS-B 3m VULB9160 HORIZONTAL

EVALUATION KITS	Vin	Vo	lo
Car Charger ACT4455- DMB-#1	10-33V	4.75-5.25V	2.1A+2.1A



ACT111A High Efficiency, Low Cost HB LED Lighting

Input Voltage	LED #	Output Current	V _{FB}	Topology
4.8 – 30VDC	1-6	1.5A	100mV	Buck

Circuit Bottom View Circuit Top View



Design Features

- 95% Efficiency
- 4.8V to 30V Input and up to 1.5A Output
- 1.4 MHz Switching & Small SOT23-6 Package
- PWM (0-100%, 0.1-10kHz) Dimming
- Thermal Shutdown & Short Circuit Protection

Operation and Application

The bridge rectifier is for AC input only. The DC input is directly connected to IN and ground. The ACT111A has an under-voltage lockout (UVLO) at 4.0V with 250mV hysteresis. When input voltage falls below 4.0V, SW stops switching. The device is activated as input voltage goes higher than 4.2V.

The LED output current is sensed by a resistor in series with the LED. The ACT111A precisely regulates the LED current by the internal EA and 0.1V reference. The average LED current is determined by the equation: $I_{LED} = 0.1V/R_{SENSE}$.

The ACT111A allows dimming with a PWM signal at the DIM pin. A signal level above 1.5V enables switching and turns LED on. To turn off the LED current, the signal level has to be below 1.52V. The dimming signal frequency range is from 100Hz to 10kHz.A 200k Ω resistor is needed to connect between FB pin R_{SENSE}. A 100pF capacitor is recommended to connect from the FB pin to ground.

Key Component Selection

An inductor with RMS rating greater than load current and its saturation current at least 30% higher should be used. Inductance value is selected to make its ripple current 20-30% of the load current. A Schottky diode (D5) is usually used for better efficiency as long as the breakdown voltage can withstand the maximum output voltage. The forward current rating of the diode must be at least equal to the maximum LED current.

For AC input, if a conventional step-down line transformer is used, a low cost IN4001can be used for D1-D4. However, if a high frequency electronic transformer is used, a Schottky diode such as SS14 should be used for high efficiency operation. For input and output capacitors, small size and low ESR ceramic capacitor is preferred.

PC Board Layout Guidance

Place input capacitor (C1) to IN pin, inductor (L1) and diode (D5) to SW pin as close as possible to reduce the voltage ringing at these pins. Place the current sense resistor (R2) close to FB pin. Minimize ground noise by connecting high current ground returns, the input capacitor ground lead, and the output filter ground lead to a single point (star ground configuration). There are two power loops in normal operation, one is formed when the SW is high and the high current flows through input capacitor (C1), internal MOSFET, inductor(L1), LEDs, R_{SENSE}(R2) to ground. The other loop is through inductor (L1), LEDs, R_{SENSE}(R2), ground to diode(D5). Make these loop areas as small as possible to minimize noise interaction.



ACT111A High Efficiency, Low Cost HB LED Lighting

Schematic (VIN=12VDC or AC, 3x350mA LEDs)



Bill of Materials

Ref.	Description	Mftr
C1	Capacitor Tantalum,100uF/16V, D Case	AVX
C2	Capacitor, Ceramic,0.01uF/50V,0603	POE
C3	Capacitor, Ceramic,100pF/25V,0603	POE
C4	Capacitor Ceramic,10uF/16V,1206	AVX
D1-D4	Diode shottoky, 40V/1A, SS14, SMA	PANJIT
D5	Schottky Barrier Rectifier,SR24,40V/2.0A,SMB	PANJIT
ZD1	Diode Zener, GLZ13A, 13V, 0.5W, MINI-MELF	PANJIT
R1	Meter Film Resistor, 30KΩ,0603, 5%	TY-OHM
R2	Meter Film Resistor, 0.28Ω,1206, 1%	TY-OHM
R4	Meter Film Resistor, 510Ω,1206, 5%	TY-OHM
L1	SMD Power Inductor,SR0604220ML,10uH,±20%	QianRu
U1	IC,ACT111,SOT23-6	Active

PCB Bottom Layer



PCB Top Layer



Typical performance characteristics



